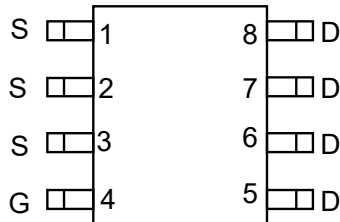


**Description**

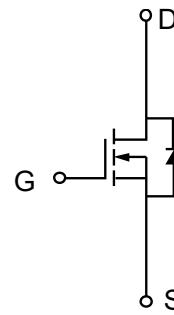
This MOSFET uses Super Trench technology that is uniquely optimized to provide the most efficient high frequency switching performance. This device provide best combination of fast switching ,low on-resistance and cost-effectiveness.

MOSFET Product Summary		
$V_{DS}(V)$	$R_{DS(on)}(m\Omega)(Typ)$	$I_D(A)$
60	5.7@ $V_{GS}=10V$	20

Top View (SOP-8)



Internal Structure

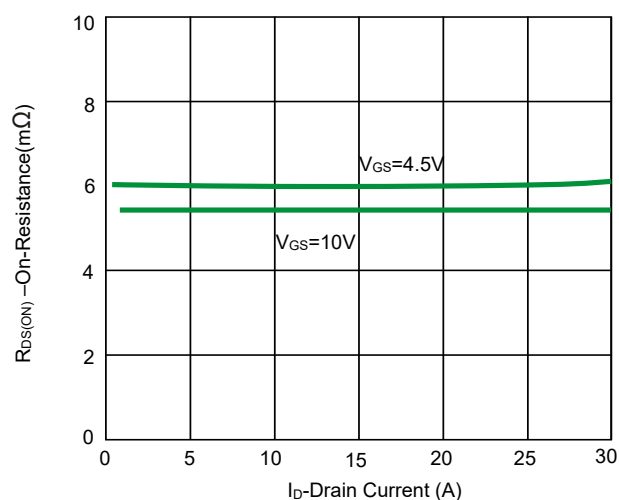
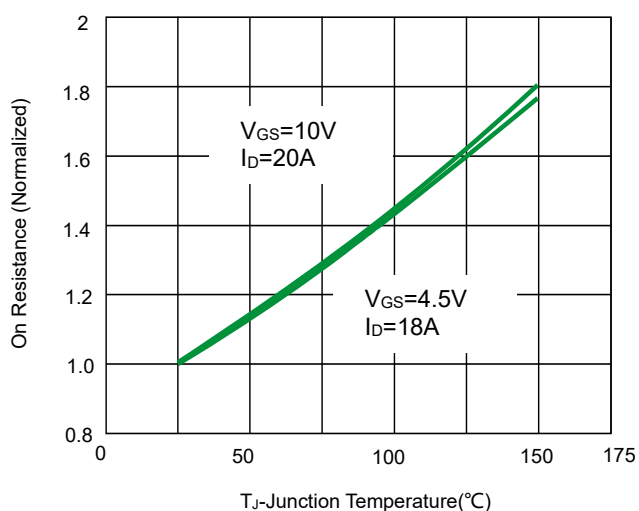

**Absolute maximum rating@25°C**

Parameter	Symbol	Maximum	Units	
Drain-Source Voltage	$V_{DS}$	60	V	
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V	
Continuous Drain Current ( $T_J=150^\circ C$ )	$I_D$	$T_A=25^\circ C$ 20	A	
		$T_A=70^\circ C$ 15		
Pulsed Drain Current	$I_{DM}$	80	A	
Maximum Power Dissipation	$P_D$	$T_A=25^\circ C$ 2.72	W	
		$T_A=70^\circ C$ 1.74		
Operating Junction and Storage Temperature Range	$T_J$	-55 to 150	$^\circ C$	
<b>Thermal Characteristics</b>				
Parameter	Symbol	Typical	Maximum	Units
Thermal Resistance-Junction to Ambient	$R_{\theta JA}$	46	62.5	$^\circ C/W$

## Electrical characteristics per line@25°C ( unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Drain-Source Breakdown Voltage	$BV_{DSS}$	$I_D = 250\mu A, V_{GS} = 0V$	60	-	-	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 60V, V_{GS} = 0V$	-	-	1.0	$\mu A$
Gate-Body Leakage Current	$I_{GSS}$	$V_{DS} = 0V, V_{GS} = \pm 20V$	-	-	$\pm 100$	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	1.0	-	2.5	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 20A$	-	5.7	8.0	m $\Omega$
		$V_{GS} = 4.5V, I_D = 18A$	-	8.0	10.5	
Drain-Source Diode Forward Voltage	$V_{SD}$	$V_{GS} = 0V, I_S = 15A$	-	0.8	1.2	V
Total Gate Charge	$Q_g$	$V_{GS} = 10V, V_{DS} = 30V, I_D = 20A$	-	67	-	nC
Gate-Source Charge	$Q_{gs}$		-	12	-	
Gate-Drain Charge	$Q_{gd}$		-	8.5	-	
Input Capacitance	$C_{ISS}$	$V_{GS} = 0V, V_{DS} = 30V, f = 1MHz$	-	4000	-	pF
Output Capacitance	$C_{OSS}$		-	680	-	pF
Reverse Transfer Capacitance	$C_{RSS}$		-	23	-	pF
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 30V, V_{GEN} = 10V, R_G = 3\Omega, R_L = 1.7\Omega, I_D = 1A$	-	11	-	ns
Turn-Off Delay Time	$t_{d(off)}$		-	56	-	ns
Turn-On Rise Time	$t_r$		-	5.0	-	ns
Turn-On Fall Time	$t_f$		-	12	-	ns
Diode Forward Current	$I_S$	-	-	-	20	A

## Typical Characteristics



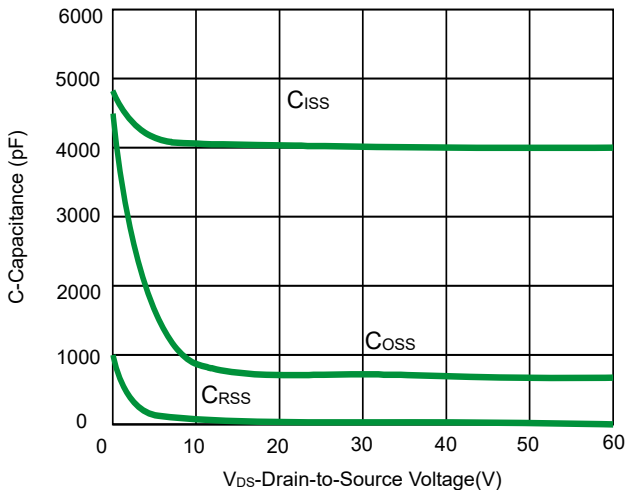


Fig 3. Capacitance vs Vds

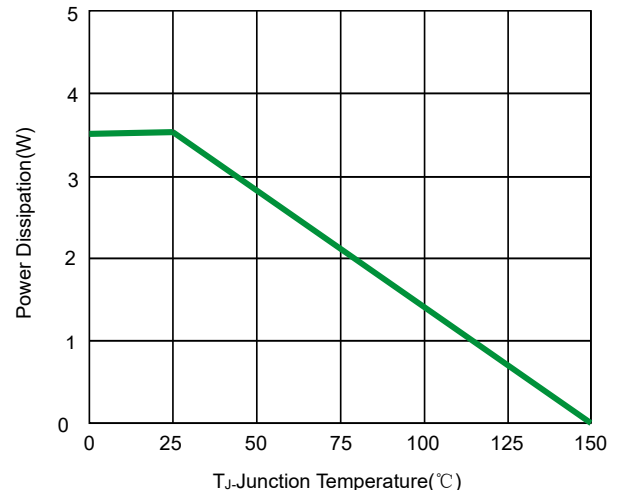


Fig 4. Power De-rating

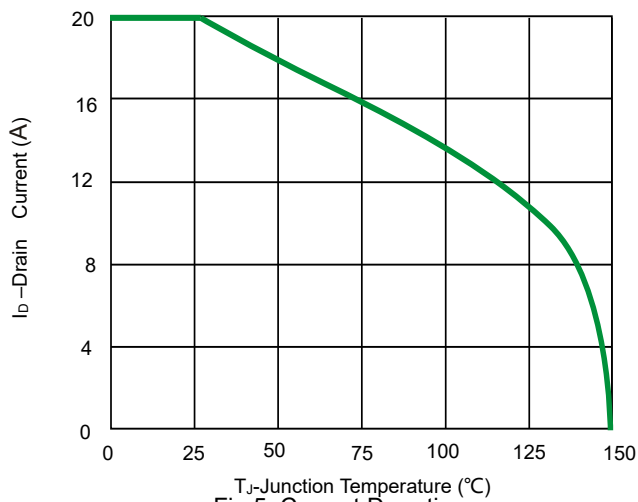


Fig 5. Current De-rating

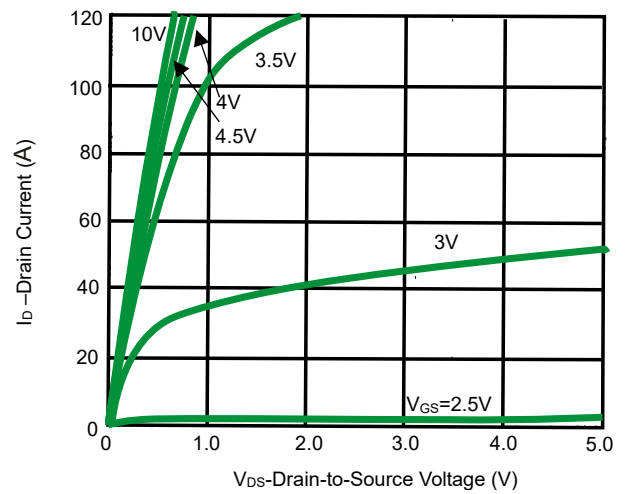


Fig 6. Output Characteristics

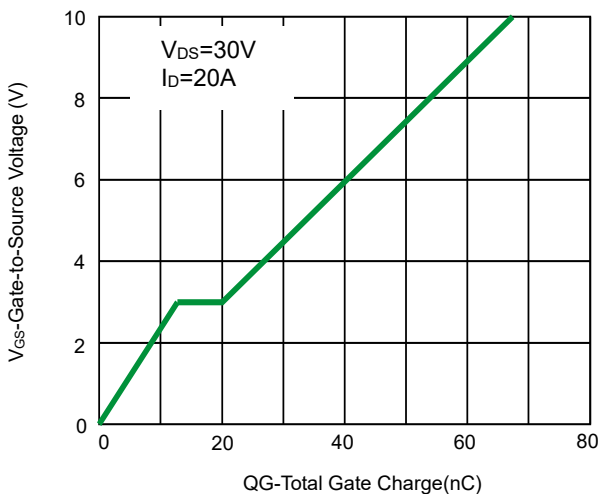


Fig 7. Gate Charge

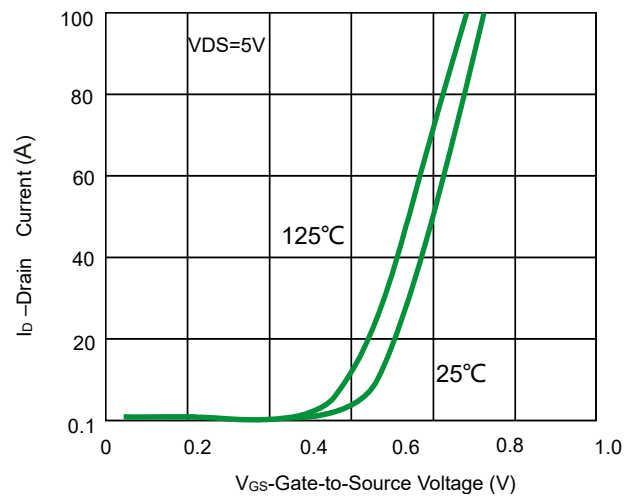


Fig 8. Transfer Characteristics

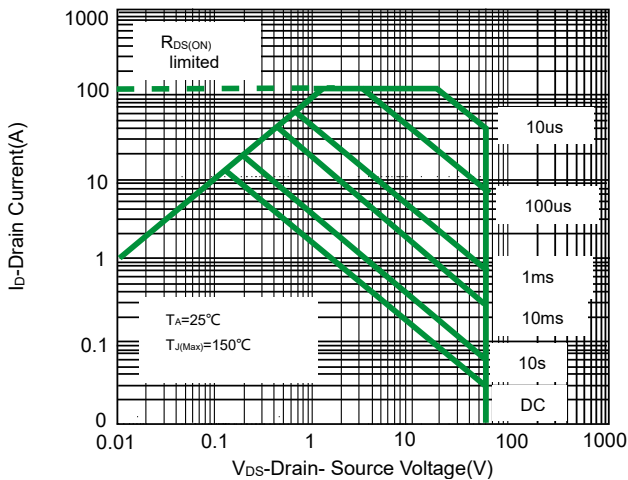


Fig 9. Safe Operating Area

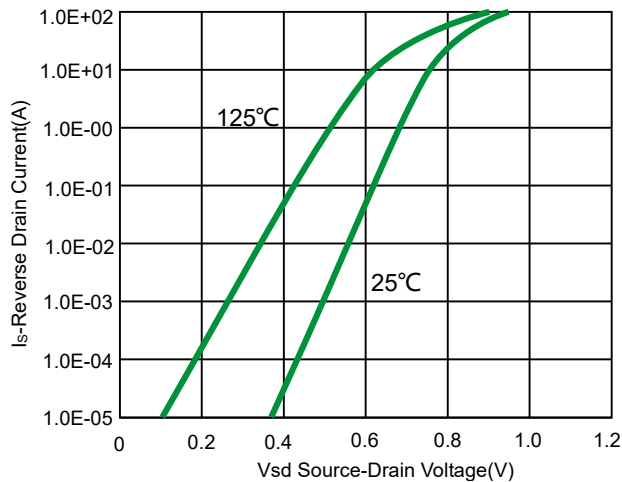


Fig 10. Source-Drain Diode Forward

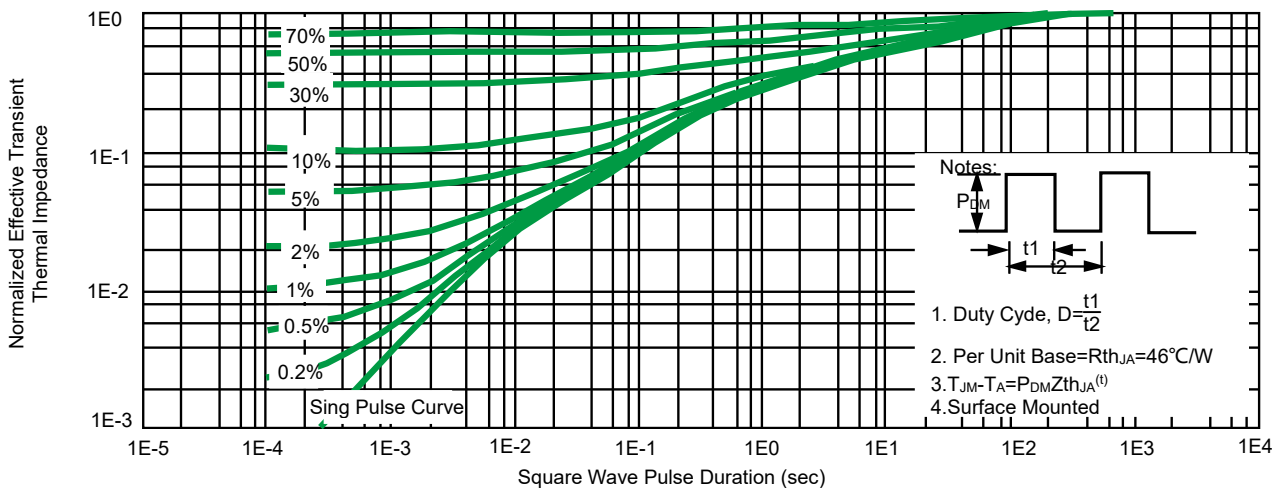
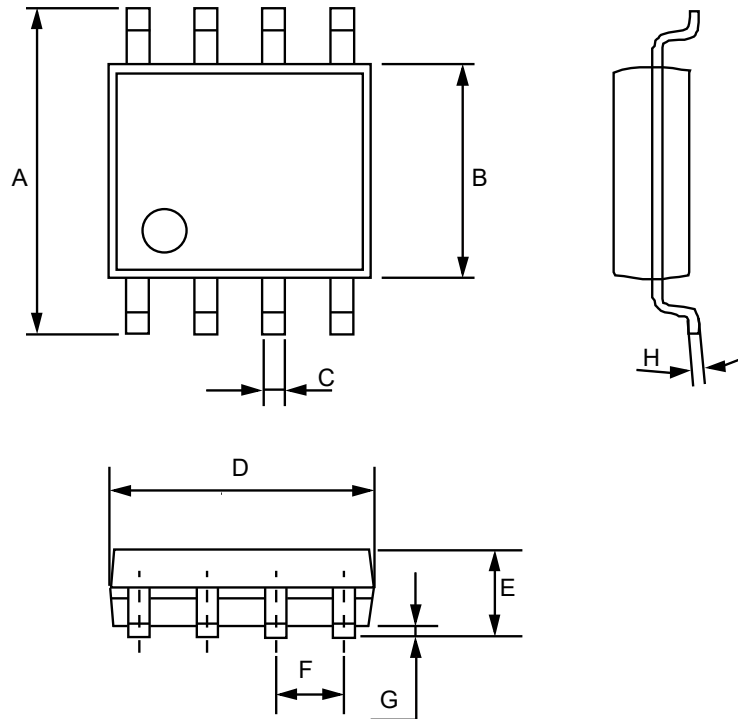


Fig 11. Normalized Thermal Transient Impedance, Junction-to-Ambient

Product dimension (SOP-8)

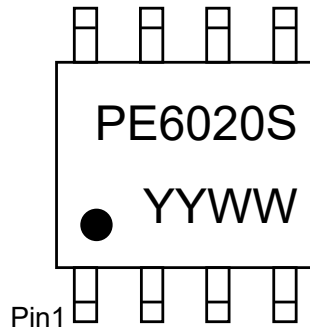


Dim	Millimeters		Inches	
	MIN	MAX	MIN	MAX
A	5.800	6.200	0.228	0.244
B	3.800	4.000	0.150	0.157
C	0.330	0.510	0.013	0.020
D	4.700	5.100	0.185	0.200
E	1.350	1.750	0.053	0.069
F	1.270 (BSC)		0.050 (BSC)	
G	0.100	0.250	0.004	0.010
H	0.170	0.250	0.006	0.010

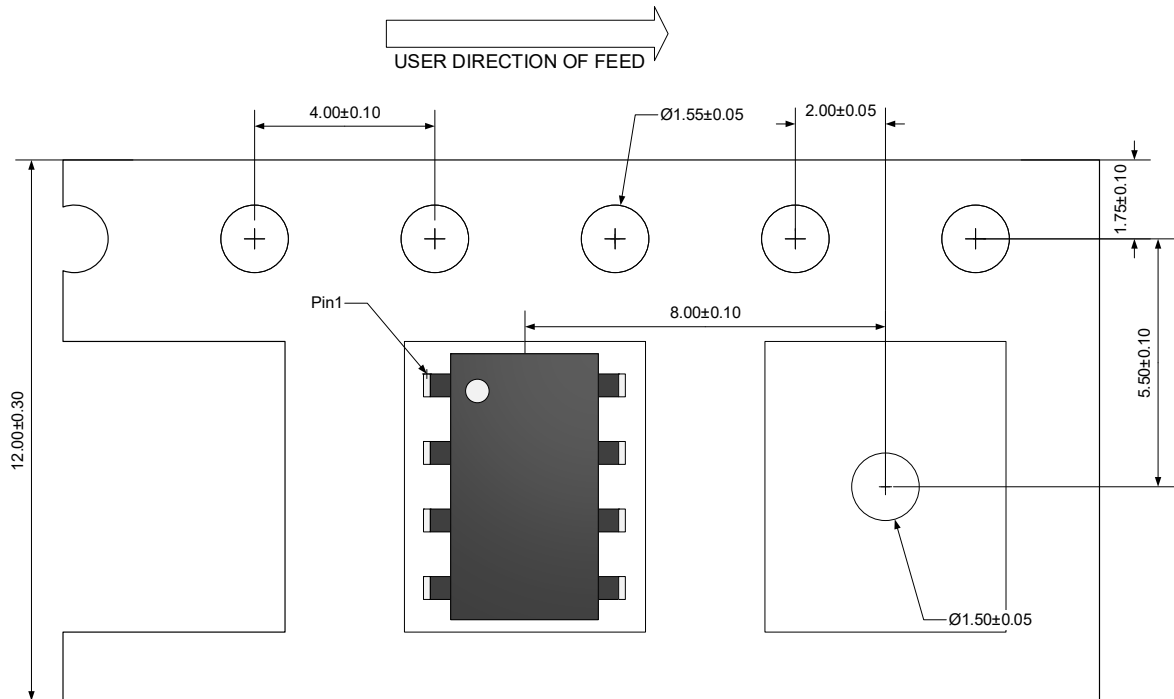
Ordering information

Device	Package	Shipping
PNM8P60V20	SOP-8	4000 / Tape & Reel

Marking information




Load with information



Unit:mm


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